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Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

- 1. (Original) A process for fabricating a microelectrode, comprising: a) providing a substrate comprising at least one polymer micro-ridge, wherein the polymer micro-ridge comprises an upper surface and two walls, the two walls forming an angle with a lower surface; b) depositing a metal thin film on the upper surface, the two walls, and the lower surface; and c) etching a predetermined amount of the deposited metal thin film on the lower surface to form the microelectrode.
- 2. (Original) The process of Claim 1, wherein etching a predetermined amount of the deposited metal thin film on the lower surface comprises wet etching, dry etching, ion beam bombardment, or any combination thereof.
- 3. (Original) The process of Claim 1, wherein providing the substrate comprising at least one polymer micro-ridge comprises molding, imprinting, photolithographic patterning, imprint lithography, or any combination thereof.
- 4. (Withdrawn) The process of Claim 1, wherein providing the substrate comprising at least one polymer micro-ridge comprises dry etching a polymer thin film.
- 5. (Original) The process of Claim 1, wherein the polymer micro-ridge comprises a linear polymer, a crosslinked polymer, an organically modified sol-gel, or any combination thereof.
- 6. (Original) The process of Claim 1, wherein the lower surface comprises silicon dioxide.
- 7. (Original) The process of Claim 1, wherein the lower surface comprises a polymer.

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8. (Original) The process of Claim 7, wherein the lower surface comprises a linear polymer, a crosslinked polymer, an organically modified sol-gel, or any combination thereof.

- 9. (Original) The process of Claim 1, wherein the polymer micro-ridge and the lower surface comprises the same polymer.
- 10. (Original) The process of Claim 1, wherein the angle between the two walls and the lower surface is about 90 degrees.
- 11. (Original) The process of Claim 1, wherein the upper surface and lower surface are substantially parallel.
- 12. (Original) The process of Claim 11, wherein the walls are substantially perpendicular to the upper surface and the lower surface.
- 13. (Original) The process of Claim 1, wherein the substrate comprises a plurality of polymer micro-ridges.
 - 14. (Original) The process of Claim 13, wherein the micro-ridges are interdigitated.
- 15. (Original) The process of Claim 1, wherein the metal thin film is selected from the group consisting of gold, platinum, titanium, and any combination thereof.
- 16. (Original) The process of Claim 1, wherein depositing the metal thin film according to a process comprises physical vapor deposition, thermal evaporation, electroplating, or any combination thereof.
- 17. (Original) A process for fabricating a microelectrode comprising: a) providing a substrate comprising at least one polymer micro-ridge, wherein the polymer micro-ridge comprises an upper surface and at least one wall, the wall forming an angle with a lower surface; b) depositing a metal thin film on the upper surface, the wall, and the lower surface; c) etching a predetermined amount of the deposited metal thin film on the lower surface or the deposited metal thin film on the upper surface; and d) etching a predetermined amount of the other of the deposited metal thin film on upper surface or the deposited metal thin film on the lower surface, thereby leaving a metal thin film on the wall.
- 18. (Original) The process of Claim 17, wherein etching a predetermined amount of the deposited metal thin film on the lower surface, upper surface, or both according to a process

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comprises wet etching, dry etching, ion beam bombardment, or any combination thereof.

19. (Original) The process of Claim 17, comprising first etching a predetermined amount of the deposited metal thin film on the upper surface, and then etching a predetermined amount of the deposited metal thin film on the lower surface.

- 20. (Original) The process of Claim 17, comprising first etching a predetermined amount of the deposited metal thin film on the lower surface, and then etching a predetermined amount of the deposited metal thin film on the upper surface.
- 21. (Original) The process of Claim 17, wherein providing the substrate comprising at least one polymer micro-ridge comprises molding, imprinting, photolithographic patterning, imprint lithography, or any combination thereof.
- 22. (Withdrawn) The method of Claim 17, wherein providing the substrate comprising at least one polymer micro-ridge comprises dry etching a polymer thin film.
- 23. (Original) The process of Claim 17, wherein the polymer micro-ridge comprises a linear polymer, a crosslinked polymer, an organically modified sol-gel, or any combination thereof.
- 24. (Original) The process of Claim 17, wherein the lower surface comprises silicon dioxide.
- 25. (Original) The process of Claim 17, wherein the lower surface comprises a polymer.
- 26. (Original) The process of Claim 25, wherein the lower surface comprises a linear polymer, a crosslinked polymer, an organically modified sol-gel, or any combination thereof.
- 27. (Original) The process of Claim 17, wherein the polymer micro-ridge and the lower surface comprise the same polymer.
- 28. (Original) The process of Claim 17, wherein the angle between the two walls and the lower surface is about 90 degrees.
- 29. (Original) The process of Claim 17, wherein the upper surface and lower surface are substantially parallel.

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30. (Original) The process of Claim 29, wherein the walls are substantially perpendicular to the upper surface and the lower surface.

- 31. (Original) The process of Claim 17, wherein the substrate comprises a plurality of polymer micro-ridges.
- 32. (Original) The process of Claim 31, wherein the polymer micro-ridges are interdigitated.
- 33. (Original) The process of Claim 17, wherein the metal thin film is selected from the group consisting of gold, platinum, titanium, and any combination thereof.
- 34. (Original) The process of Claim 17, wherein depositing the metal thin film according to a process comprises physical vapor deposition, thermal evaporation, electroplating, or any combination thereof.